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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/324,823	06/02/1999	TAKESHI IDE	P99.0654	2056
33448	7590	07/08/2004	EXAMINER	
ROBERT J. DEPKE LEWIS T. STEADMAN HOLLAND & KNIGHT LLC 131 SOUTH DEARBORN 30TH FLOOR CHICAGO, IL 60603			MOE, AUNG SOE	
			ART UNIT	PAPER NUMBER
			2612	

DATE MAILED: 07/08/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary

Application No.

09/324,823

Applicant(s)

IDE ET AL.

Examiner

Aung S. Moe

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-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☐ Responsive to communication(s) filed on ____.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-18 is/are pending in the application.
- 4a) Of the above claim(s) ____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) ____ is/are allowed.
- 6) ☒ Claim(s) 1-18 is/are rejected.
- 7) ☐ Claim(s) ____ is/are objected to.
- 8) ☐ Claim(s) ____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on ____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☒ All b) ☐ Some * c) ☐ None of:
1. ☒ Certified copies of the priority documents have been received.
 2. ☐ Certified copies of the priority documents have been received in Application No. ____.
 3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413)
Paper No(s)/Mail Date. ____. |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | 5) <input type="checkbox"/> Notice of Informal Patent Application (PTO-152) |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date ____. | 6) <input type="checkbox"/> Other: ____. |

DETAILED ACTION

Response to Arguments

1. Applicant's arguments filed 5/25/2004 have been fully considered but they are not persuasive.

Regarding claims 1-6, the Applicant alleged that (i.e., page 8 of the remarks) that Suzuki '703 merely teaches that dynamic range can be altered by changing the substrate voltage but requires application of three distinct substrate voltages (i.e., col. 12, lines 50+). There is no such requirement in the instant application. Furthermore, Applicants submit that there is no disclosure whatsoever regarding the structures described in the newly submitted claims

In response to applicant's argument above, it is noted that whether or not using three distinct substrate voltages is considered critical, because they are not recited in **the rejected claim(s)**. Although the claims are interpreted in light of the specification, limitations from the specification are not read into the claims. See *In re Van Geuns*, 988 F.2d 1181, 26 USPQ2d 1057 (Fed. Cir. 1993).

In this case, Suzuki '703 clearly teaches the controlling of the bias voltage so that the bias voltage in the progressive mode (i.e., the Frame mode where the image data are readout as in a non-interlaced manner by applying the respective substrate-bias voltage Vsub Level 2 as discussed in col. 2, lines 10+ and col. 12, lines 60+ of Suzuki '703; see Figs. 7A-7D) to be smaller than the bias voltage while operating in the interlaced mode (i.e., noted from the Fig. 7C of Suzuki '703 that the Vsub LEVEL2 for the Frame Mode for producing the image data in a non-interlaced manner is less than the Vsub LEVEL1 of the Filed mode for producing the

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interlaced image for displaying the moving image on the EVF 44; see Fig. 7A-7D & 10; and col. 2, lines 1-10, col. 12, line 35+ and col. 13, lines 1+) as recited in present claimed invention.

In view of the above, having the system of Yamaguchi '921 and then given the well-established teaching of Suzuki '703, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the system of Yamaguchi '921 as taught by Suzuki '407, since Suzuki '407 states at col. 19, lines 5+ that such a modification would increase the signal-to-noise ratio in both Full frame reading mode and the Field reading mode so that it is possible to obtain a high-quality image regardless of whether the operation is performed in the field reading mode or in the full frame reading mode.

Regarding claims 13-18, the Examiner asserts that the use of any/only one of two possible substrate voltage is taught by Suzuki '703. For example, Suzuki '703 teaches that during the interlace mode (i.e., Field mode) only/any possible substrate voltage applied to the substrate is either V_{sub} Level 0 or V_{sub} Level 1, and moreover, during the progressive mode (i.e., Frame mode) only/any possible substrate voltage applied to the substrate is either V_{sub} Level 0 or V_{sub} Level 2. Therefore, any/only one of two possible substrate voltages are applied to the substrate when the sensor is used in a specific mode.

In view of the above reasons, the Examiner will maintain the rejections as set forth below.

Applicant's arguments with respect to claims 7-12 have been considered but are moot in view of the new ground(s) of rejection.

Claim Rejections - 35 USC § 103

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

3. Claims 1-2, 4-5, 13-14 and 16-17 are rejected under 35 U.S.C. 103(a) as being unpatentable over Yamaguchi et al. (U.S. 6,342,921) in view of Suzuki et al. (U.S. 6,515,703).

Regarding claim 1, Yamaguchi '921 discloses a solid-state image sensor (Figs. 1, 19, 28 and 29) device having an image sensing portion performing photoelectric conversion in both progressive mode in which all picture element signals are output independently (i.e., noted the Frame mode for reading all the pixels in a progressive manner as discussed in col. 1, lines 15+), and interlace mode in which interlaced scanning are performed and the picture element signals obtained in respective scanning in said image sensing portion being superimposed (i.e., noted that during the interlaced mode, one field of image data is reading out as an odd field and an

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even field, so that such field data are superimposed to display the moving images as discussed in col. 1, lines 25), and the sensor device comprising: a photodiode within the image sensing portion (Fig. 11, the elements 2; col. 11, lines 60-65).

Furthermore, it is noted that although Yamaguchi '921 discloses the CCD device capable of operating at both the progressive mode (i.e., Full frame mode for capturing a still image as discussed in col. 1, lines 20+) and the interlaced mode (i.e., the moving/monitor mode for capturing and displaying a moving image as discussed in col. 1, lines 30+) by applying the respective bias voltage to control the potential of charges stored in the CCD sensor during the different operation mode (i.e., see col. 12, lines 25+, col. 14, lines 5+ and col. 15, lines 5+), Yamaguchi '921 does not explicitly show the use of a substrate-bias generation circuit for applying a basis voltage to the substrate of said image sensing portion and for controlling said bias voltage in said progressive mode (Frame mode) to be smaller than the bias voltage while operating in the interlaced mode (Field mode) as recited in present claimed invention.

However, the above-mentioned claimed limitations are well known in the art as evidenced by Suzuki '703. In particular, Suzuki '703 discloses that it is conventionally well-known in the art to use a substrate-bias generation circuit for applying a basis voltage (i.e., Fig. 1, the elements' 2, 3 and 4) to the substrate of said image sensing portion (i.e., the CCD sensor of the camera as shown in Fig. 7A-7D of Suzuki '703) and for controlling said bias voltage in said progressive mode (i.e., the Frame mode where the image data are readout as in a non-interlaced manner by applying the respective substrate-bias voltage V_{sub} Level 2 as discussed in col. 2, lines 10+ and col. 12, lines 60+ of Suzuki '703; see Figs. 7A-7D) to be smaller than the bias voltage while operating in the interlaced mode (i.e., noted from the Fig. 7C of Suzuki '703 that

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the Vsub LEVEL2 for the Frame Mode for producing the image data in a non-interlaced manner is less than the Vsub LEVEL1 of the Filed mode for producing the interlaced image for displaying the moving image on the EVF 44; see Fig. 7A-7D & 10; and col. 2, lines 1-10, col. 12, line 35+ and col. 13, lines 1+) as recited in present claimed invention.

In view of the above, having the system of Yamaguchi '921 and then given the well-established teaching of Suzuki '703, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the system of Yamaguchi '921 as taught by Suzuki '407, since Suzuki '407 states at col. 19, lines 5+ that such a modification would increase the signal-to-noise ratio in both Full frame reading mode and the Field reading mode so that it is possible to obtain a high-quality image regardless of whether the operation is performed in the field reading mode or in the full frame reading mode.

Regarding claim 4, the combination of Yamaguchi '921 and Suzuki '703 shows wherein the substrate bias generation circuit adjusts the substrate bias voltage during the progressive mode of operation such that a potential difference is generated between a doped region (i.e., As shown in Figs. 7B-7C, noted the n-TYPE SUBSTRATE regions of Suzuki '703) and a well of the photodiode (i.e., noted the P-LAYER as shown in Figs. 7B-7C of Suzuki '703) which is greater than during the interlaced operation (i.e., as shown in Figs. 7A-7C, noted the potential difference of the Vsub LEVEL 2 and Vsub LEVEL1 for the respective regions of the image sensor as taught by Suzuki '703).

Regarding claims 2 and 5, it is noted that the method Claims 2 and 5 corresponding to the product claims 1 and 4, thus claims 2 and 5 are rejected for the same reasons as set forth for the claims 1 and 4 as discussed above.

Regarding claims 13-14 and 16-17, it is noted that the combination of Yamaguchi '921 and Suzuki '703 teaches wherein any/only one of two possible substrate voltages are applied to the substrate (i.e., see Fig. 7C of Suzuki '703; Suzuki '703 teaches that during the interlace mode (i.e., Field mode) only/any possible substrate voltage applied to the substrate is either V_{sub} Level 0 or V_{sub} Level 1, and moreover, during the progressive mode (i.e., Frame mode) only/any possible substrate voltage applied to the substrate is either V_{sub} Level 0 or V_{sub} Level 2. Therefore, any/only one of two possible substrate voltages are applied to the substrate when the sensor is used in a specific mode, e.g., Frame/Progressive or Field/Interlace mode).

4. Claims 1-6, 13-15 and 16-18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chang (U.S. 5,264,939) in view of Suzuki '703 (U.S. 6,515,703).

Regarding claim 1, Chang '939 discloses a solid-state image sensor (Figs. 1 and 2) device having an image sensing portion performing photoelectric conversion in both progressive mode in which all picture element signals are output independently (i.e., noted the Full Frame transfer mode during the non-interlaced reading as discussed in col. 4, lines 40+), and interlace mode in which of interlaced scanning are performed and the picture element signals obtained in respective scanning in said image sensing portion are superimposed (i.e., noted during the interlaced mode, an odd field and an even field are superimposed in an interlaced manner for displaying moving images; see col. 4, lines 6+); and the sensor device comprising: a photodiode

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(col. 3, lines 40+ and col. 5, lines 55+) within the image sensing portion and applying the respective substrate voltages during the operation of different modes (i.e., the interlaced mode and the non-interlaced/progressive mode; see Figs. 2-4).

Furthermore, it is noted that although Chang '939 discloses the CCD device (Fig. 2) capable of operating at both the progressive mode (i.e., Non-interlaced mode for reading the image frame as discussed in col. 4, lines 40+) and the interlaced mode (i.e., the interlaced mode for capturing and displaying a moving image as discussed in col. 4, lines 5+) by applying the respective substrate voltages to the image sensor as shown in Figs. 2 and 3-4, Chang '939 does not explicitly show wherein a basis voltage applied to the substrate of said image sensing portion and for controlling said bias voltage in said progressive mode to be smaller than said voltage in said interlaced mode as recited in present claimed invention.

However, the above-mentioned claimed limitations are well known in the art as evidenced by Suzuki '703. In particular, Suzuki '703 discloses that it is conventionally well-known in the art to use a substrate-bias generation circuit for applying a basis voltage (i.e., Fig. 1, the elements' 2, 3 and 4) to the substrate of said image sensing portion (i.e., the CCD sensor of the camera as shown in Fig. 7A-7D of Suzuki '703) and for controlling said bias voltage in said progressive mode (i.e., the Frame mode where the image data are readout as in a non-interlaced manner by applying the respective substrate-bias voltage $V_{\text{sub Level 2}}$ as discussed in col. 2, lines 10+ and col. 12, lines 60+ of Suzuki '703; see Figs. 7A-7D) to be smaller than the bias voltage while operating in the interlaced mode (i.e., noted from the Fig. 7C of Suzuki '703 that the $V_{\text{sub LEVEL2}}$ for the Frame Mode for producing the image data in a non-interlaced manner is less than the $V_{\text{sub LEVEL1}}$ of the Filed mode for producing the interlaced image for

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displaying the moving image on the EVF 44; see Fig. 7A-7D & 10; and col. 2, lines 1-10, col. 12, line 35+ and col. 13, lines 1+) as recited in present claimed invention.

In view of the above, having the system of Chang '939 and then given the well-established teaching of Suzuki '703, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the system of Chang '939 as taught by Suzuki '407, since Suzuki '407 states at col. 19, lines 5+ that such a modification would increase the signal-to-noise ratio in both Full frame reading mode and the Field reading mode so that it is possible to obtain a high-quality image regardless of whether the operation is performed in the field reading mode or in the full frame reading mode.

Regarding claim 4, the combination of Chang '939 and Suzuki '703 shows wherein the substrate bias generation circuit adjusts the substrate bias voltage during the progressive mode of operation such that a potential difference is generated between a doped region (i.e., As shown in Figs. 7B-7C, noted the n-TYPE SUBSTRATE regions of Suzuki '703) and a well of the photodiode (i.e., noted the P-LAYER as shown in Figs. 7B-7C of Suzuki '703) which is greater than during the interlaced operation (i.e., as shown in Figs. 7A-7C, noted the potential difference of the V_{sub} LEVEL 2 and V_{sub} LEVEL1 for the respective regions of the image sensor as taught by Suzuki '703).

Regarding claim 2, Chang '939 discloses a drive method for a solid-state image sensor device (i.e., Figs. 1 and 3-4) having an image sensing portion including a photodiode (20) within the image sensing portion for performing photoelectric conversion said image sensing portion operation in both progressive mode in which all picture element signals are output independently

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(i.e., noted the Full Frame transfer mode during the non-interlaced reading as discussed in col. 4, lines 40+), and interlaced mode in which pluralities of scanning are performed and picture element signals obtained in respective scanning are superimposed (i.e., noted during the interlaced mode, an odd field and an even field are superimposed in an interlaced manner for displaying moving images; see col. 4, lines 6+).

Furthermore, it is noted that although Chang '939 discloses the CCD device capable of operating at both the progressive mode (i.e., Full frame mode for capturing a still image as discussed in col. 1, lines 20+) and the interlaced mode (i.e., during the interlaced mode, an odd field and an even field is superimposed in an interlaced manner for displaying moving images; see col. 4, lines 6+), and the method including the step of applying the respective voltage to the substrate of the CCD sensor (i.e., see Fig. 2) during the interlaced mode and the non-interlaced mode (i.e., see Figs. 3-4), Chang '939 does not explicitly show wherein in applying a bias voltage to the substrate of said image sensing portion, in said progressive mode the value of said bias voltage is smaller than that in said interlace mode as recited in present claimed invention.

However, the above-mentioned claimed limitations are well known in the art as evidenced by Suzuki '703. In particular, Suzuki '703 discloses that it is conventionally well-known in the art to use a substrate-bias generation circuit for applying a basis voltage (i.e., Fig. 1, the elements' 2, 3 and 4) to the substrate of said image sensing portion (i.e., the CCD sensor of the camera as shown in Fig. 7A-7D of Suzuki '703) and for controlling said bias voltage in said progressive mode (i.e., the Frame mode where the image data are readout as in a non-interlaced manner by applying the respective substrate-bias voltage V_{sub} Level 2 as discussed in col. 2, lines 10+ and col. 12, lines 60+ of Suzuki '703; see Figs. 7A-7D) to be smaller than the bias

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voltage while operating in the interlaced mode (i.e., noted from the Fig. 7C of Suzuki '703 that the Vsub LEVEL2 for the Frame Mode for producing the image data in a non-interlaced manner is less than the Vsub LEVEL1 of the Filed mode for producing the interlaced image for displaying the moving image on the EVF 44; see Fig. 7A-7D & 10; and col. 2, lines 1-10, col. 12, line 35+ and col. 13, lines 1+) as recited in present claimed invention.

In view of the above, having the system of Chang '939 and then given the well-established teaching of Suzuki '703, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the system of Chang '939 as taught by Suzuki '407, since Suzuki '407 states at col. 19, lines 5+ that such a modification would increase the signal-to-noise ratio in both Full frame reading mode and the Field reading mode so that it is possible to obtain a high-quality image regardless of whether the operation is performed in the field reading mode or in the full frame reading mode.

Regarding claim 5, please see the Examiner's comments with respect to claim 4 as discussed above.

Regarding claim 3, Chang '939 discloses a camera (Fig. 1) comprising a solid-state image sensor device (16) having an image sensing portion (Fig. 2) for performing photoelectric conversion (i.e., see Fig. 3, col. 3, lines 40+) and a substrate-bias generation circuit (i.e., Fig. 1, the elements 64, 30, and 32), an optical system (14) receiving incident light from a subject and forming an image on said image sensing portion of said solid-state image sensor device (16), and a signal processing system for processing the signals output from said solid-state image sensor device to obtain a video signal (i.e., see Fig. 1, the elements' 24, 26, 28, and 44-62; noted the use of NTSC standard video signals), wherein the image sensing portion (Fig. 2) includes a

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photodiode structure (i.e., col. 3, lines 40 and col. 5, lines 56), and wherein said driving system selectively operates in (i.e., noted that the imaging system of Chang '939 is capable of operating both in a non-interlaced/Frame mode and the interlace mode for displaying the moving image therein; see col. 3, lines 55+ and col. 4, lines 5+) operate in progressive mode in which all picture element signals are output independently (i.e., noted the Full-Frame/non-interlaced transfer mode as discussed in col. 4, lines 40+), and interlaced mode in which pluralities of scanning are performed (i.e., the scanning for the odd fields and the even fields for producing the interlaced image signals) and the picture element signals obtained in respective scanning are superimposed (i.e., noted during the interlaced mode, an odd field and an even field are superimposed in an interlaced manner for displaying moving images; see col. 4, lines 6+).

Furthermore, it is noted that although Chang '939 discloses the CCD device capable of operating at both the progressive mode (i.e., Full-frame/non-interlaced mode for capturing an image as discussed in col. 4, lines 40+) and the interlaced mode (i.e., the moving/monitor mode for capturing the odd/even fields and displaying a moving image as discussed in col. 4, lines 5+) by applying the respective substrate voltages to the image sensor as shown in Figs. 2-4, Chang '939 does not explicitly show that the bias voltage to be applied to the substrate in said progressive mode being controlled to be smaller than that in said interlaced mode by said substrate-bias generation circuit as recited in the present claimed invention.

However, the above-mentioned claimed limitations are well known in the art as evidenced by Suzuki '703. In particular, Suzuki '703 discloses that it is conventionally well-known in the art to use a substrate-bias generation circuit for applying a basis voltage (i.e., Fig. 1, the elements' 2, 3 and 4) to the substrate of said image sensing portion (i.e., the CCD sensor of

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the camera as shown in Fig. 7A-7D of Suzuki '703) and for controlling said bias voltage in said progressive mode (i.e., the Frame mode where the image data are readout as in a non-interlaced manner by applying the respective substrate-bias voltage V_{sub} Level 2 as discussed in col. 2, lines 10+ and col. 12, lines 60+ of Suzuki '703; see Figs. 7A-7D) to be smaller than the bias voltage while operating in the interlaced mode (i.e., noted from the Fig. 7C of Suzuki '703 that the V_{sub} LEVEL2 for the Frame Mode for producing the image data in a non-interlaced manner is less than the V_{sub} LEVEL1 of the Filed mode for producing the interlaced image for displaying the moving image on the EVF 44; see Fig. 7A-7D & 10; and col. 2, lines 1-10, col. 12, line 35+ and col. 13, lines 1+) as recited in present claimed invention.

In view of the above, having the system of Chang '939 and then given the well-established teaching of Suzuki '703, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the system of Chang '939 as taught by Suzuki '407, since Suzuki '407 states at col. 19, lines 5+ that such a modification would increase the signal-to-noise ratio in both Full frame reading mode and the Field reading mode so that it is possible to obtain a high-quality image regardless of whether the operation is performed in the field reading mode or in the full frame reading mode.

Regarding claim 6, the combination of Chang '939 and Suzuki '703 shows wherein the substrate bias generation circuit adjusts the substrate bias voltage during the progressive mode of operation such that a potential difference is generated between a doped region (i.e., As shown in Figs. 7B-7C, noted the n-TYPE SUBSTRATE regions of Suzuki '703) and a well of the photodiode (i.e., noted the P-LAYER as shown in Figs. 7B-7C of Suzuki '703) which is greater than during the interlaced operation (i.e., as shown in Figs. 7A-7C, noted the potential difference

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of the V_{sub} LEVEL 2 and V_{sub} LEVEL1 for the respective regions of the image sensor as taught by Suzuki '703).

Regarding claims 13-15 and 16-18, it is noted that the combination of Chang '939 and Suzuki '703 teaches wherein any/only one of two possible substrate voltages are applied to the substrate (i.e., see Fig. 7C of Suzuki '703; Suzuki '703 teaches that during the interlace mode (i.e., Field mode) only/any possible substrate voltage applied to the substrate is either V_{sub} Level 0 or V_{sub} Level 1, and moreover, during the progressive mode (i.e., Frame mode) only/any possible substrate voltage applied to the substrate is either V_{sub} Level 0 or V_{sub} Level 2. Therefore, any/only one of two possible substrate voltages are applied to the substrate when the sensor is used in a specific mode, e.g., Frame/Progressive or Field/Interlace mode).

5. Claims 7-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Chang '939 in view of Suzuki '703 as applied to claims discussed above and further in view of Lee et al. (U.S. 5,371,033).

Regarding claims 7-12, although the combination of Chang '939 and Suzuki '703 teaches that a potential of a vertical transfer device portion and a read-out gate are controlled by a common electrode (i.e., noted the electrode element over the VCCD and P layer as shown in Fig.

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7B of Suzuki '703), the combination of Chang '939 and Suzuki '703 does not explicitly show a light shielding structure extends over the common electrode to the photodiode as claimed.

However, the above-mentioned claimed limitations are well known in the art as evidenced by Lee '033. In particular, Lee '033 teaches that it is conventionally well known in the art to use a light shielding structure (i.e., an optical shield conductor layer 42) extends over the common electrode (40) to the photodiode (i.e., noted the light receiving region as shown in Figs. 1 and 3) as claimed.

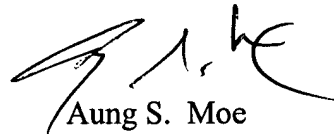
In view of the above, having the system of Chang '939 and then given the well-established teaching of Suzuki '703, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the system of Chang '939 as taught by Suzuki '407, since Suzuki '407 states at col. 2, lines 45+ that such a modification would improved the characteristic of long wave length and avoid a smear characteristic thereof.

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Aung S. Moe whose telephone number is 703-306-3021. The examiner can normally be reached on Mon-Fri (9-5).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wendy Garber can be reached on 703-305-4929. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).



Aung S. Moe
Primary Examiner
Art Unit 2612

A. Moe
June 28, 2004